Analog Power AM7420N

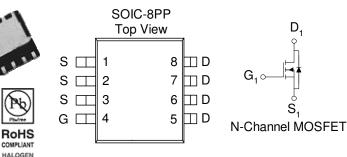
N-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe SOIC-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$			
20	$2.5 @ V_{GS} = 10V$	37			
20	$4 @ V_{GS} = 4.5V$	29			



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Limit	Units		
Drain-Source Voltage			20	V	
Gate-Source Voltage		V_{GS}	±8	v	
Continuous Drain Current ^a	T _A =25°C	T_	±37	A	
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ъ	±30		
Pulsed Drain Current ^b	I_{DM}	±50			
Continuous Source Current (Diode Conduction) ^a		I_S	2.3	A	
Payran Dissination ^a	$T_A=25^{\circ}C$	D _D	5.0	W	
Power Dissipation ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	I D	3.2		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

FREE

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
a	t <= 10 sec	r.	25	°C/W		
Maximum Junction-to-Ambient ^a	Steady State	R _{0JA}	65	°C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Danamatan	Cymrh ol	Trad Con Pittana	Limits			T 124	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static	•		-		-	-	
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	0.7			V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Drain Current	¹ DSS	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A	
Drain-Source On-Resistance ^A	r	$V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$			2.5	mΩ	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 1 \text{ A}$			4		
Forward Tranconductance ^A	${f g}_{ m fs}$	$V_{DS} = 15 \text{ V}, I_{D} = 1 \text{ A}$		40		S	
Diode Forward Voltage	V_{SD}	$I_S = 1 A, V_{GS} = 0 V$		0.7		V	
Dynamic ^b							
Total Gate Charge	Q_{g}	V - 15 V V - 4 5 V		100			
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 1 \text{ A}$		20		nC	
Gate-Drain Charge	Q_{gd}	1 _D – 1 A		20			
Turn-On Delay Time	$t_{d(on)}$			50			
Rise Time	$t_{\rm r}$	$V_{DD} = 25 \text{ V}, R_L = 25 \Omega, I_D = 1 \text{ A},$		90		nS	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 V$		300		113	
Fall-Time	t_{f}			100			

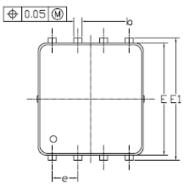
Notes

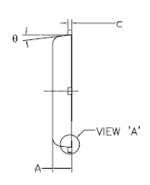
a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

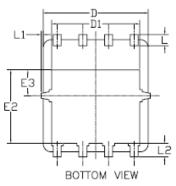
b. Guaranteed by design, not subject to production testing.

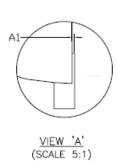
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Package Information









SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
31 MBOL3	MIN	NOM	MAX	MIN	NOM	MAX	
A	0.85	0.95	1.00	0.033 0.037 0.0			
A1	0.00		0.05	0.000 — 0.00			
b	0.30	0.40	0.50	0.012 0.016 0.0			
С	0. 15	0. 20	0. 25	0.006	0.008	0.010	
D	5. 20 BSC				0.205 BSC		
D1	4.35 BSC			0.171 BSC			
Е	5. 55 BSC			0.219 BSC			
E1	6.05 BSC				0.238 BSC		
E2	3. 625 BSC			0.143 BSC			
E3	1. 275 BSC				0.050 BSC		
e	1.27 BSC				0.050 BSC		
L	0.45	0. 55	0.65	0.018	0.022	0.026	
L1	0		0.15	0		0.006	
L2	0.68 REF			0.027 REF			
θ	0°		10°	0°		10°	